Pseudopotentials

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How to abstract atoms in solid?





Background: Atomic Orbitals

 $_{*}(r,\theta,\phi)$

r radial

 θ polar

 ϕ azimutha



• Hydrogen eigenstates ($\rho = v_{xc} = 0$)



Hydrogen Eigenstates



See notes on (1) Laplacian in spherical coordinates & (2) Schrodinger equation for spherically symmetric potentials

Herman-Skillman Solutions for Atoms

• Hartree approximation ($v_{xc} = 0$) for many-electron interaction



Outer shells (*i.e.*, larger *n*) still spread outward

For the inclusion of xc potential, see notes on (1) Numerical integration of radial wave function & (2) Kohn-Sham potential

Atomic Orbitals



sp³ Hybridization: Pauling's Note (1930)

Colculations such as these are sumplified by the fact that for a complete 3 athogonal transformation the sum of the squares of the coefficients for a quien mittal signer " is unity. Four equivalent bonds pour p3. max. value. $H_{mn} = \frac{1}{2}(x + x + y + z)$ Helex in 2 soular Kiley SAM サデデ= ±(ル + + + - 2) 4777= = = + (2 + x+ y+ 2) It may be significant that we get 4 tetraledrally-We can paint one & along the 2 aris, ray. directed bonds, each with the maximum 4、= シャキ星、ス possible strongth 42= 20 - 23 + Ex (assuming Ro= Rp). This 43= さの一方マーた×+花子 SARS 4= さかー ホマー ママイー たみ means that if Rs happens to squal Rp, two bonds The coeffict sis '2 to make the 4's equivalent. or three bounds will be Then the coeffo. of 2 are fixed for norm. * or the . strongest when at titrahedral angles. But if Ros stretches out for they than Rp. (which it actually does for name Zeff.), then things are different. Let us assume max &= maxp=1. Then da (a+(1-2)=0, a= = ? Maximim paraible = 12=1.414 In this case two strong bonds will be oppositely directed (Insis nobeenle), three will Twobends, Maysolue lie i a plane, four towards tetrahedron - 1.414 5- - 1.414 Three gouds: 1.392 corners. Four squal 1.366

Charge Density at GaAs/Si (111) Interface



- Highest occupied states in Si have the hybrid sp³ character
- Occupied GaAs states are As p-like (lowest unoccupied states are s-like)



Projection of Kohn-Sham wave functions onto atomic orbitals

		Band	Ga 4s	Ga 4p	Ga 4d	As 4s	As 4p	As 4d	Total
		1150	0.0000	0.1157	0.0708	0.0000	0.8033	0.0101	1
		1151	0.0000	0.1158	0.0709	0.0000	0.8033	0.0100	1
	Occupied	1152	0.0000	0.1166	0.0713	0.0000	0.8017	0.0104	1
Unoccupied		1153	0.6763	0.0000	0.0000	0.3236	0.0001	0.0000	1

Z. Yuan et al., J. Appl. Phys. 114, 074316 ('13); Nano Lett. 13, 4925 ('13)

Wave Functions in MoSe₂ Bilayer

dxv

d_x2_y2

d,2

- Highest occupied states (blue) are d_{z2}-like
- Lowest unoccupied states (red) are d_{xv}-like





Valence Electrons

• Example: Silicon — 1s²2s²2p⁶3s²3p²

WebElements[™] periodic table



Electronic Configuration

The following represents the electronic configuration and its associated term symbol for the **ground state neutral gaseous atom**. The configuration associated with silicon in its compounds is not necessarily the same.

- Ground state electron configuration: [Ne].3s².3p²
- Shell structure: 2.8.4

Abstraction: Pseudopotential



Norm-Conserving Pseudopotential

Construct pseudopotentials such that:

- **1.** Pseudowave functions, $R_l^{PP}(r)$ (l = 0, 1, 2, ...), contain no nodes
- 2. $R_l^{PP}(r)$ coincides with the all-electron wave function $R_l^{AE}(r)$ beyond a cutoff radius r_{cl}
- **3.** The charge enclosed within r_{cl} for the AE- & pseudo-wave functions must be equal $\int_{0}^{r_{cl}} 4\pi r^{2} dr \left| R_{l}^{PP}(r) \right|^{2} = \int_{0}^{r_{cl}} 4\pi r^{2} dr \left| R_{l}^{AE}(r) \right|^{2}$
- **4.** AE- & pseudo-eigenenergies must be identical $E_l^{PP} = E_l^{AE}$
- **5.** Conditions 2 & 4 imply: the logarithmic derivatives of the two wave functions must match at r_{cl}

$$\frac{1}{R_l^{\text{PP}}(r,E_l)} \frac{dR_l^{\text{PP}}(r,E_l)}{dr} \bigg|_{r=r_{\text{c}l}} = \frac{1}{R_l^{\text{AE}}(r,E_l)} \frac{dR_l^{\text{AE}}(r,E_l)}{dr} \bigg|_{r=r_{\text{c}l}}$$

Troullier & Martins, Phys. Rev. B 41, 1993 ('91)

See notes on (1) Norm-conserving pseudopotential & (2) Logarithmic derivative

Local & Nonlocal Pseudopotentials

Ionic pseudopotential operator

$$\hat{V}_{ion}^{PP}(r) = V_{ion,local}^{PP}(r) + \sum_{l,m} |lm\rangle \Delta V_l(r) \langle lm|$$
Common to all
angular momenta
Angular-momentum
dependent
(Example) Polyethylene slab without & with external electry



See notes on (1) Nonlocal pseudopotential & (2) Fully nonlocal pseudopotential

Projector-Augmented Wave (PAW)

• Core-charge correction significantly increases the transferability $\tilde{v}_{xc}(\mathbf{r}) = v_{xc}([\rho_{PS}], \mathbf{r}) + [v_{xc}([\rho_{PS} + \rho_{core}], \mathbf{r}) - v_{xc}([\rho_{PS}], \mathbf{r})]$

Louie, Froyen & Cohen, *Phys. Rev. B* **50**, 1738 ('82)

• An "all-electron" electronic structure calculation that separates smooth pseudowave functions & rapidly varying all electron wave functions by using projection function



• For practical construction of pseudopotentials, see T. Sugahara *et al.*, *Phys. Rep. Kumamoto Univ.* **12**, 279 ('06)